

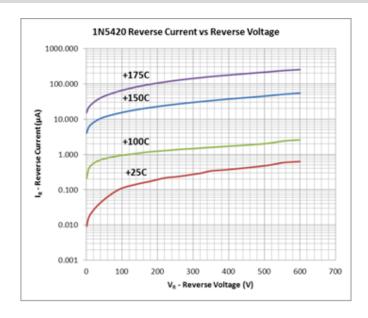
3A FAST RECOVERY RECTIFIERS

TECHNICAL DATA DATA SHEET 125, REV E

RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Recovery Time (t _{rr}) 1N5415/US, 1N5416,US 1N5417,US, 1N5418,US 1N5419/US, 1N5420,US	I _f = 0.5A, I _r = 1.0A, I _{rr} = 0.25A	-	-	150 150 250 400	nsec
Thermal Resistance (θ _{JL})	d = 0.375"	1	-	22	° C/W
Thermal Resistance (θ _{JC})	L=0 for US versions	-	-	6.5	° C/W

^{*}Sensitron **space equivalent diodes** are manufactured and screened to MIL-PRF-19500 flow and guidelines starting from wafer fabrication through assembly and testing using our internal specification.

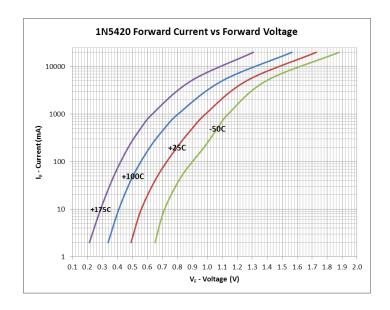
GRAPHS:

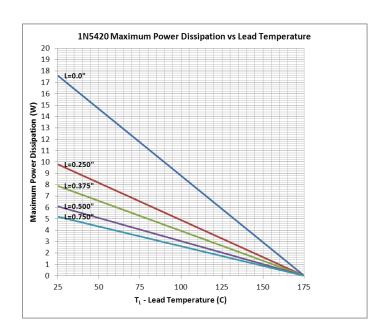




SENSITRON SEMICONDUCTOR

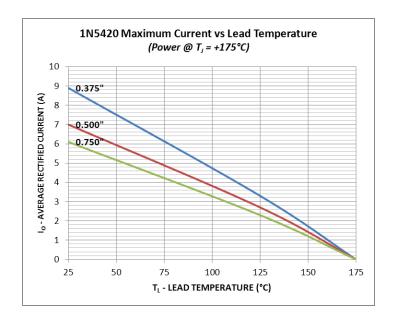
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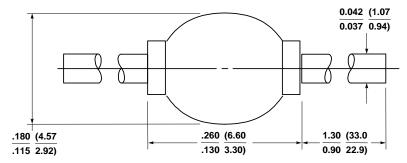
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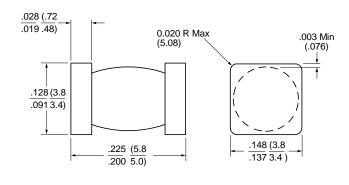


PACKAGE DIMENSIONS (inches/mm)

AXIAL (PKG 301)



MELF (Add "US" to part number)





1N5415/US thru 1N5420/US

SENSITRON SEMICONDUCTOR

3A FAST RECOVERY RECTIFIERS

TECHNICAL DATA DATA SHEET 125, REV E

PART ORDERING INFORMATION

The following part numbers can be screened and tested to the military screening flow. The parts are marked in accordance with the testing performed, example:

Sensitron Screening Level	*Part Number Leaded Package (example for 1N5415)	*Part Number Surface Mount Package (example for 1N5415US)	
1N	1N5415	1N5415US	
JAN	JAN1N5415	JAN1N5415US	
JANTX	JANTX1N5415	JANTX1N5415US	
JANTXV	JANTXV1N5415	JANTXV1N5415US	
SJ	SJ5415	SJ5415US	
SX	SX5415	SX5415US	
sv	SV5415	SV5415US	
JANS	JANS1N5415	JANS1N5415US	
SS	SS5415	SS5415US	

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